## NSN 5961-01-243-3508

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| Internal Configuration:   |
|---|
| Junction contact  |
| Semiconductor Material:   |
| Silicon   |
| Voltage Rating In Volts Per Characteristic:                                       |
| 200.0 repetitive peak reverse voltage and 200.0 repetitive peak off-state voltage |
| Current Rating Per Characteristic:  |
| 7.40 amperes forward current, total rms horsepower metric                         |
| Power Rating Per Characteristic:  |
| 5.0 watts small-signal input power, common-collector blank                        |
| Special Features:   |
| Junction pattern arrangement: pnpn  |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
|   |
| Demilitarization:   |
| No  |
| Fiig:   |
| A110a0  |
|   |
|   |